# RC4558, RM4558 DUAL GENERAL-PURPOSE OPERATIONAL AMPLIFIERS

SLOS073A - MARCH 1976 - REVISED JUNE 1999

- Continuous-Short-Circuit Protection
- Wide Common-Mode and Differential Voltage Ranges
- No Frequency Compensation Required
- Low Power Consumption
- No Latch-Up
- Unity-Gain Bandwidth . . . 3 MHz Typ
- Gain and Phase Match Between Amplifiers
- Low Noise . . . 8 nV√Hz Typ at 1 kHz
- Designed To Be Interchangeable With Raytheon RC4558 and RM4558 Devices

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## description

The RC4558 and RM4558 devices are dual general-purpose operational amplifiers with each half electrically similar to the μA741 except that offset null capability is not provided.

The high common-mode input voltage range and the absence of latch-up make these amplifiers ideal for voltage-follower applications. The devices are short-circuit protected and the internal frequency compensation ensures stability without external components.

The RC4558 is characterized for operation from 0°C to 70°C, and the RM4558 is characterized for operation over the full military temperature range of –55°C to 125°C.

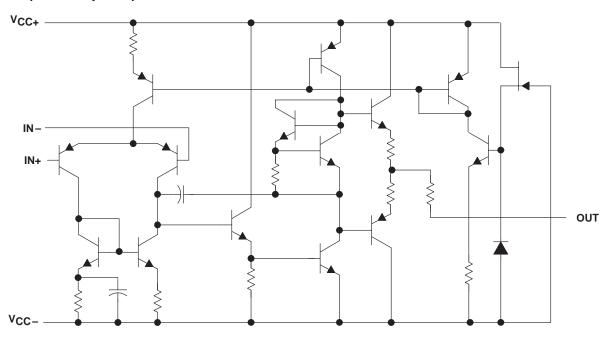
#### **AVAILABLE OPTIONS**

	V <sub>IO</sub> MAX	PACKAGED DEVICES							
TA	AT 25°C	SMALL OUTLINE (D)	SSOP (DBR)	CERAMIC DIP (JG)	PLASTIC DIP (P)	SOP (PSR)			
0°C to 70°C	6 mV	RC4558D	RC4558DBR	_	RC4558P	RC4558PSR			
−55°C to 125°C	6 mV	_	_	RM4558JG	_	_			

The D package is available taped and reeled. Add the suffix R to the device type (e.g., RC4558DR).

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### schematic (each amplifier)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		RC4558	RM4558	UNIT	
Supply voltage (see Note 1)	V <sub>CC+</sub>	18	22	V	
Supply voltage (see Note 1)	VCC-	-18	-22	V	
Differential input voltage (see Note 2)		±30	±30	V	
Input voltage (any input, see Notes 1 and 3)	±15	±15	V		
Duration of output short circuit to ground, one amplifier at a time (see Note 4)	unlimited	unlimited			
	D package	197			
Package thermal impedance, θ <sub>JA</sub> (see Note 5)	P package	10	)4	°C/W	
	PS package	16			
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG package		300	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or P package	260		°C		
Storage temperature range, T <sub>stg</sub>	-65 to 150	-65 to 150	°C		

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.

- 2. Differential voltages are at IN+ with respect to IN-.
- 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
- 4. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
- 5. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

#### recommended operating conditions

	MIN	MAX	UNIT	
Supply voltage	V <sub>CC+</sub>	5	15	\/
Supply voltage	V <sub>CC</sub> -	<b>-</b> 5	-15	l v
Oneverting free circumnately to Tr	RC4558	0	70	°C
Operating free-air temperature, T <sub>A</sub>	RM4558	-55	125	C



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# electrical characteristics at specified free-air temperature, $V_{CC+}$ = 15 V, $V_{CC-}$ = -15 V

PARAMETER		TEST CONDITIONS†		RC4558			RM4558			UNIT	
	TO WHE I WIN			1E31 CONDITIONS		TYP	MAX	MIN	TYP	MAX	UNIT
				25°C		0.5	6		0.5	5	
VIO	Input offset voltage	V <sub>O</sub> = 0	Full			7.5			6	mV	
				range		5	200			200	
l <sub>IO</sub>	Input offset current		V <sub>O</sub> = 0	25°C Full		5	200		5	200	nA
٥١١٥	input onset current			range			300			500	I na
				25°C		150	500		140	500	
I <sub>IB</sub>	Input bias current		VO = 0	Full			800			1500	nA
.,				range							.,
VICR	Common-mode input voltage ran	ige	D: 40 l-0	25°C	±12	±14		±12	±14		V
			$R_L = 10 \text{ k}\Omega$	25°C 25°C	±12	±14		±12	±14		-
VOM	Maximum output voltage swing		$R_L = 2 k\Omega$	Full	±10	±13		±10	±13		· V
			$R_L \ge 2 k\Omega$	range	±10			±10			
	Large-signal differential voltage		R <sub>L</sub> ≥ 2 kΩ,	25°C	20	300		50	350		V/mV
AVD	amplification		$V_O = \pm 10 \text{ V}$	Full range	15			25			
B <sub>1</sub>	Unity-gain bandwith			25°C		3		2	3.5		MHz
rį	Input resistance			25°C	0.3	5		0.3	5		ΜΩ
CMRR	Common-mode rejection ratio			25°C	70	90		70	90		dB
k <sub>SVS</sub>	Supply-voltage sensitivity (ΔV <sub>IO</sub> /	ΔV <sub>CC</sub> )	$V_{CC} = \pm 15 V$ to $\pm 9 V$	25°C		30	150		30	150	μV/V
V <sub>n</sub>	Equivalent input noise voltage (c	losed loop)	$A_{VD} = 100,$ $R_{S} = 100 \Omega,$ $f = 1 \text{ kHz},$ $BW = 1 \text{ Hz}$	25°C		8			8		nV√Hz
			V <sub>O</sub> = 0,	25°C		2.5	5.6		2.5	5.6	
ICC	Supply current (both amplifiers)	Supply current (both amplifiers)				3	6.6		3	6.6	mA
			No load	T <sub>A(max)</sub>		2.3	5		2	5	
	Total power dissipation (both amplifiers)		V <sub>O</sub> = 0, No load	25°C		75	170		75	170	
$P_{D}$				T <sub>A(min)</sub>		90	200		90	200	mW
				T <sub>A(max)</sub>		70	150		60	150	
V <sub>O1</sub> /V <sub>O2</sub>	Crosstalk attenuation	Open loop	$R_S = 1 k\Omega$ ,	25°C		85			85		dB
017.02	A <sub>VD</sub> = 100		f = 10 kHz	200		105			105		

<sup>†</sup> All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is 0°C to 70°C for RC4558 and –55°C to 125°C for RM4558. Ta(min) is 0°C for RC4558 and –55°C for RM4558. Ta(max) is 70°C for RC4558 and 125°C for RM4558.

# operating characteristics, $V_{CC+} = 15 \text{ V}$ , $V_{CC-} = -15 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER		MIN	TYP	MAX	UNIT		
t <sub>r</sub>	Rise time	\/ı = 20 m\/	Pr = 2 kO	C <sub>1</sub> = 100 pF		0.13		ns
	Overshoot	$V_I = 20 \text{ mV}, \qquad R_L = 2 \text{ k}\Omega,$		CL = 100 pr		5%		
SR	Slew rate at unity gain	V <sub>I</sub> = 10 V,	$R_L = 2 k\Omega$ ,	$C_L = 100 pF$	1.1	1.7		V/μs



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